

Data sheet acquired from Harris Semiconductor SCHS170B

November 1997 - Revised October 2003

High-Speed CMOS Logic Dual 4-Input Multiplexer

Features

- Common Select Inputs
- Separate Output-Enable Inputs
- Three-State Outputs
- Fanout (Over Temperature Range)
 - Standard Outputs......10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I $_I \leq 1 \mu A$ at $V_{OL},\,V_{OH}$

Description

The CD74HC253 and CD74HCT253 are dual 4-to-1 line selector/multiplexers having three-state outputs. One of four sources for each section is selected by the common select inputs, S0 and S1. When the output enable $(\overline{10E}, \overline{20E})$ is HIGH, the output is in the high-impedance state.

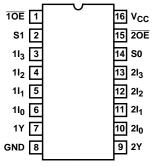
Ordering Information

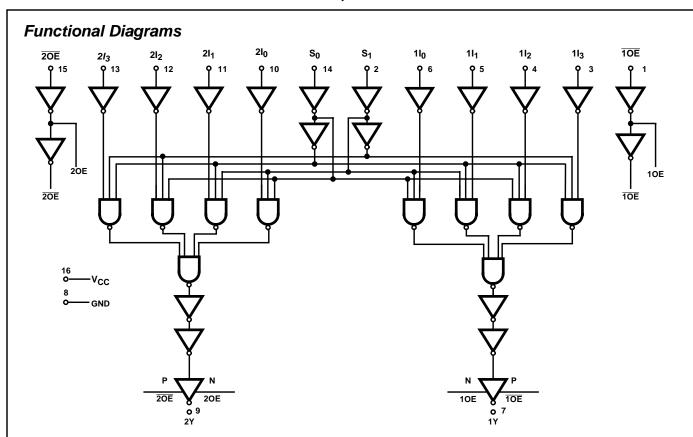
| PART NUMBER | TEMP. RANGE (°C) | PACKAGE |
|---------------|------------------|------------|
| CD74HC253E | -55 to 125 | 16 Ld PDIP |
| CD74HC253M | -55 to 125 | 16 Ld SOIC |
| CD74HC253MT | -55 to 125 | 16 Ld SOIC |
| CD74HC253M96 | -55 to 125 | 16 Ld SOIC |
| CD74HCT253E | -55 to 125 | 16 Ld PDIP |
| CD74HCT253M | -55 to 125 | 16 Ld SOIC |
| CD74HCT253MT | -55 to 125 | 16 Ld SOIC |
| CD74HCT253M96 | -55 to 125 | 16 Ld SOIC |

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD74HC253, CD74HCT253 (PDIP, SOIC) TOP VIEW





TRUTH TABLE

| | INPUTS te 1) | | DATA I | OUTPUT ENABLE | ОИТРИТ | | |
|----|-----------------|----------------|----------------|------------------|--------|---|---|
| S1 | S0 | I ₀ | I ₁ | l ₃ | ŌĒ | Y | |
| Х | Х | Х | Х | Х | Х | Н | Z |
| L | L | L | Х | Х | Х | L | L |
| L | L | Н | Х | Х | Х | L | Н |
| L | Н | Х | L | Х | Х | L | L |
| L | Н | Х | Н | Х | Х | L | Н |
| Н | L | Х | Х | L | Х | L | L |
| Н | L | Х | Х | Н | Х | L | Н |
| Н | Н | Х | Х | Х | L | L | L |
| Н | Н | Х | X | Х | Н | L | Н |

H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High Impedance (Off). NOTE:

1. Select inputs S1 and S0 are common to both sections.

Absolute Maximum Ratings

| DC Supply Voltage, V _{CC} 0.5V to | 7V |
|---|----|
| DC Input Diode Current, I _{IK} | |
| For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ | mΑ |
| DC Output Diode Current, I _{OK} | |
| For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ | mΑ |
| DC Drain Current, per Output, I _O | |
| For -0.5V < V _O < V _{CC} + 0.5V | mΑ |
| DC Output Source or Sink Current per Output Pin, IO | |
| For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$ | mΑ |
| DC V _{CC} or Ground Current, I _{CC} | nΑ |
| | |

Thermal Information

| Thermal Resistance (Typical, Note 2) | θ _{JA} (°C/W) |
|--|------------------------|
| E (PDIP) Package | 67 |
| M (SOIC) Package | 73 |
| Maximum Junction Temperature | |
| Maximum Storage Temperature Range6 | 65°C to 150°C |
| Maximum Lead Temperature (Soldering 10s) | 300°C |
| (SOIC - Lead Tips Only) | |

Operating Conditions

| Temperature Range, T _A 55°C to 125°C Supply Voltage Range, V _{CC} |
|---|
| HC Types |
| HCT Types |
| DC Input or Output Voltage, V _I , V _O 0V to V _{CC} |
| Input Rise and Fall Time |
| 2V |
| 4.5V 500ns (Max) |
| 6V |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

| | | TES CONDI | | V _{CC} | 25°C | | | -40°C TO 85°C | | -55°C TO 125°C | | |
|--------------------------|-----------------|------------------------------------|---------------------|-----------------|------|-----|------|---------------|------|----------------|------|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | | | | | | | | | | | | |
| High Level Input | V _{IH} | - | - | 2 | 1.5 | i | - | 1.5 | - | 1.5 | - | V |
| Voltage | | | | 4.5 | 3.15 | • | - | 3.15 | - | 3.15 | - | V |
| | | | | 6 | 4.2 | - | - | 4.2 | - | 4.2 | - | V |
| Low Level Input | V _{IL} | - | - | 2 | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| Voltage | | | | 4.5 | - | - | 1.35 | - | 1.35 | - | 1.35 | V |
| | | | | 6 | - | - | 1.8 | - | 1.8 | - | 1.8 | V |
| High Level Output | V _{OH} | V _{IH} or V _{IL} | -0.02 | 2 | 1.9 | - | - | 1.9 | - | 1.9 | - | V |
| Voltage CMOS Loads | | | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| Owied Eddas | | | -0.02 | 6 | 5.9 | - | - | 5.9 | - | 5.9 | - | V |
| High Level Output | | | - | - | - | - | - | - | - | - | - | V |
| Voltage TTL Loads | | | -6 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| 112 20005 | | | -7.8 | 6 | 5.48 | - | - | 5.34 | - | 5.2 | - | V |
| Low Level Output | V _{OL} | V _{IH} or V _{IL} | 0.02 | 2 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Voltage CMOS Loads | | | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Owo Educa | | | 0.02 | 6 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output | | | - | - | - | - | - | - | - | - | - | V |
| Voltage TTL Loads | | | -6 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| | | | -7.8 | 6 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | Ι _Ι | V _{CC} or GND | - | 6 | - | - | ±0.1 | - | ±1 | - | ±1 | μА |

DC Electrical Specifications (Continued)

| | | TES CONDIT | | v _{cc} | | 25°C | | -40°C 1 | O 85°C | -55°C TO 125°C | | |
|--|------------------------------|------------------------------------|---|-----------------|------|------|------|---------|--------|----------------|-----|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| Quiescent Device Current | Icc | V _{CC} or GND | 0 | 6 | - | - | 8 | - | 80 | - | 160 | μА |
| HCT TYPES | | | | | | | | | | | | |
| High Level Input Voltage | V _{IH} | - | - | 4.5 to 5.5 | 2 | - | - | 2 | - | 2 | - | V |
| Low Level Input Voltage | V _{IL} | - | - | 4.5 to 5.5 | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| High Level Output Voltage CMOS Loads | V _{OH} | V _{IH} or V _{IL} | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| High Level Output Voltage TTL Loads | | | -4 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Low Level Output Voltage CMOS Loads | V _{OL} | V _{IH} or V _{IL} | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output Voltage TTL Loads | | | 4 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | lį | V _{CC} and GND | 0 | 5.5 | - | - | ±0.1 | - | ±1 | - | ±1 | μΑ |
| Quiescent Device Current | I _{CC} | V _{CC} or GND | 0 | 5.5 | - | - | 8 | - | 80 | - | 160 | μА |
| Additional Quiescent Device Current Per Input Pin: 1 Unit Load | ΔI _{CC} (Note 3) | V _{CC} -2.1 | - | 4.5 to 5.5 | - | 100 | 360 | - | 450 | - | 490 | μА |
| Three-State Leakage Current | l _{OZ} | V _{IL} or V _{IH} | V _O = V _{CC} or GND | 5.5 | - | - | ±0.5 | - | ±5 | - | ±10 | μА |

NOTE:

3. For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

HCT Input Loading Table

| INPUT | UNIT LOADS |
|--|------------|
| 1l _O - 1l ₃ , 2l _O -2l ₃ | 0.4 |
| 1E _O , 2E _O , S ₀ , S ₁ | 1 |

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

Switching Specifications Input t_r, t_f = 6ns

| | | TEST | V _{CC} | 25°C | | | -40°C TO 85°C | | -55°C TO 125°C | | |
|-------------------|------------------|-----------------------|-----------------|------|-----|-----|------------------|-----|-------------------|-----|-------|
| PARAMETER | SYMBOL | CONDITIONS | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | - | | | | | | | | | | |
| Propagation Delay | , | C _L = 50pF | 2 | - | - | 175 | - | 220 | - | 265 | ns |
| Select to Outputs | t _{PHL} | | 4.5 | - | - | 35 | - | 44 | - | 53 | ns |
| | | C _L =15pF | 5 | - | 14 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 30 | - | 37 | - | 45 | ns |

Switching Specifications Input t_r , t_f = 6ns (Continued)

| | | TEST | v _{cc} | | 25°C | | | С ТО °С | | C TO 5°C | |
|--|--|-----------------------|-----------------|-----|------|-----|-----|------------|-----|-------------|-------|
| PARAMETER | SYMBOL | CONDITIONS | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| Data to Outputs | t _{PLH,} | C _L = 50pF | 2 | - | - | 175 | - | 220 | - | 265 | ns |
| | t _{PHL} | | 4.5 | - | - | 35 | - | 44 | - | 53 | ns |
| | | C _L =15pF | 5 | - | 14 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 30 | - | 37 | - | 45 | ns |
| Disable Delay Times | t _{PHZ} , t _{PLZ} | C _L = 50pF | 2 | - | - | 150 | - | 190 | - | 225 | ns |
| | | C _L = 50pF | 4.5 | - | - | 30 | - | 38 | - | 45 | ns |
| | | CL = 15pF | 5 | - | 12 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 26 | - | 33 | - | 38 | ns |
| Enable Delay Times | t _{PZH} , | C _L = 50pF | 2 | - | - | 110 | - | 140 | - | 165 | ns |
| | tPZL | CL = 50pF | 4.5 | - | - | 22 | - | 28 | - | 33 | ns |
| | | CL = 15pF | 5 | - | 9 | - | - | - | - | - | ns |
| | | CL = 50pF | 6 | - | - | 19 | - | 24 | - | 28 | ns |
| Output Transition Times | t _{TLH} , t _{THL} | C _L = 50pF | 2 | - | - | 60 | - | 75 | - | 90 | ns |
| | | | 4.5 | - | - | 12 | - | 15 | - | 18 | ns |
| | | | 6 | - | - | 10 | - | 13 | - | 15 | ns |
| Input Capacitance | Cl | - | - | - | - | 10 | - | 10 | - | 10 | pF |
| Three-State Output Capacitance | СО | - | - | - | - | 20 | - | 20 | - | 20 | pF |
| Power Dissipation Capacitance (Notes 4, 5) | C _{PD} | - | 5 | - | 46 | - | - | - | - | - | pF |
| HCT TYPES | | | | | • | | | | | | |
| Propagation Delay Select to Outputs | t _{PLH} , t _{PHL} | C _L = 50pF | 4.5 | _ | - | 40 | - | 50 | - | 60 | ns |
| | | C _L =15pF | 5 | - | 16 | - | - | | - | - | ns |
| Data to Outputs | t _{PLH} , | C _L = 50pF | 4.5 | - | - | 38 | - | 48 | - | 57 | ns |
| | t _{PHL} | C _L =15pF | 5 | - | 16 | - | - | - | - | - | ns |
| Disable Delay Times | t _{PLH} , | C _L = 50pF | 4.5 | - | | 30 | - | 38 | - | 45 | ns |
| | t _{PHL} | C _L =15pF | 5 | - | 12 | - | - | - | - | - | ns |
| Enable Delay Times | t _{PZH} , | C _L = 50pF | 4.5 | - | - | 30 | - | 38 | - | 45 | ns |
| | t _{PZL} | C _L =15pF | 5 | - | 12 | - | - | - | - | - | ns |
| Output Transition Time | t _{TLH} , t _{THL} | C _L = 50pF | 4.5 | - | - | 12 | - | 15 | - | 18 | ns |
| Input Capacitance | C _{IN} | - | - | - | - | 10 | - | 10 | - | 10 | pF |
| Three-State Output Capacitance | СО | - | - | - | - | 20 | - | 20 | - | 20 | pF |
| Power Dissipation Capacitance (Notes 4, 5) | C _{PD} | - | 5 | - | 52 | - | - | - | - | - | pF |

^{4.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per multiplexer.

^{5.} $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

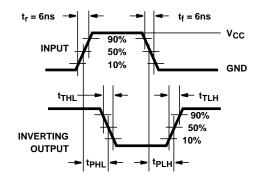


FIGURE 1. HC AND HCT TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

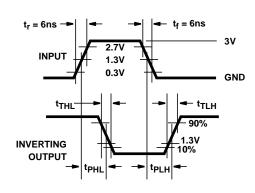


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

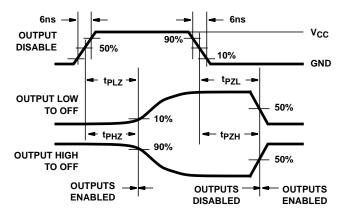


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

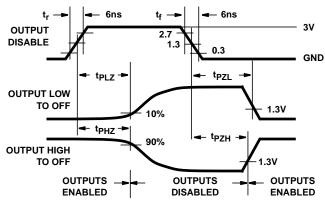
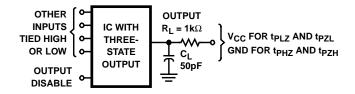


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

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PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| CD74HC253E | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | (6) NIPDAU | N / A for Pkg Type | -55 to 125 | CD74HC253E | Samples |
| CD74HC253M | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC253M | Samples |
| CD74HC253MT | ACTIVE | SOIC | D | 16 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC253M | Samples |
| CD74HCT253E | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -55 to 125 | CD74HCT253E | Samples |
| CD74HCT253EE4 | ACTIVE | PDIP | N | 16 | 25 | TBD | Call TI | Call TI | -55 to 125 | | Samples |
| CD74HCT253M | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT253M | Samples |
| CD74HCT253M96 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT253M | Samples |
| CD74HCT253MG4 | ACTIVE | SOIC | D | 16 | 40 | TBD | Call TI | Call TI | -55 to 125 | | Samples |
| CD74HCT253MT | ACTIVE | SOIC | D | 16 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT253M | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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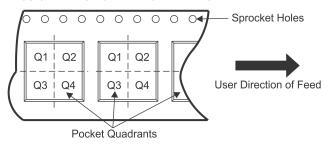
TAPE AND REEL INFORMATION





| | | Dimension designed to accommodate the component width |
|---|----|---|
| E | 30 | Dimension designed to accommodate the component length |
| K | (0 | Dimension designed to accommodate the component thickness |
| | Ν | Overall width of the carrier tape |
| F | 21 | Pitch between successive cavity centers |

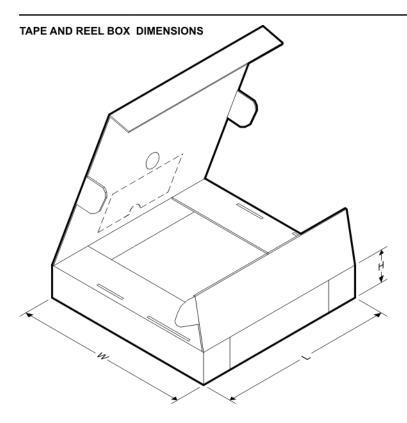
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CD74HCT253M96 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |

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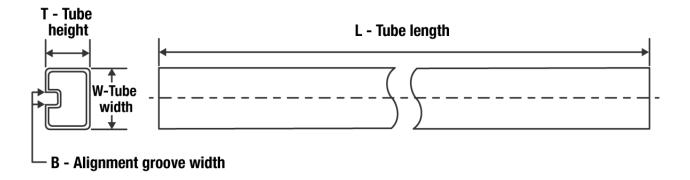
*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CD74HCT253M96 | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

| Device Package Name | | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|---------------------|---------------|--------------|------|-----|--------|--------|--------|--------|
| CD74HC253E | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| CD74HC253E | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| CD74HC253M | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| CD74HCT253E | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| CD74HCT253E | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| CD74HCT253EE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| CD74HCT253EE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| CD74HCT253M | CD74HCT253M D | | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| CD74HCT253MG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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